Chemical deposition of large area Silver Sulphide flms

Dhumure S.S.*and Lokhande C.D.

*Ramkrishana Paramhansa Mahavidyalaya, Osmanabad, 413501, MS Department of Physics, Shivaji University, Kolhapur, 416 004, India

Abstract- In this communication, we report on the chemical deposition of large area (50 cm^2) of Ag₂ S films from an acidic medium using thioacetamide as a sulphur source. The effect of deposition temperature from 8 to 55° c was studied.

INTRODUCTION

of Ag₂ S have The films been deposited onto chemically glass, steel stainless and titanium substrates, using thioacetamide as a sulphur source. The preparative parameters have been optimized. The reaction mechamism for deposition from acidic medium have been proposed. Thin, reflecting adhesive and polycrystalline Ag₂ S films were studied. The electrical resistivity, microstructure and XRD of the films have studied. Photo electrochemical cells showed that, the films are in type and photoactive in nature.

EXPERIMENTAL

Aqueous solution (5 ml of o.1M) silver nitrate and (15 ml of 0.5 M) thioacetamide were mixed together in a beaker. To it, glass substrates were immersed, after being attached to a holder and stirred continuously during deposition. The pH of the solution was 2.5. The solution colour was changed to blakesh and after 30 mins. Films were taken out of the bath, washed with double distilled water and preserved in an air tight container. The films were adhesive uniform to the substrates. In this study, for the deposition at 8°c the solution were cooled down at 8°C with ice bath, before mixing, the reaction mixture was placed in a constant bath temperature maintained at 8°c for 30 mins. Studies of the optical absorption of the films were carried out using UV-VIS - NIR spectrophotometer. The structure of the films was determined by X –ray diffraction pattern using

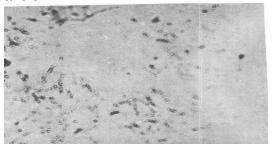
Cukα radiation with Philips pw 1710 diffractometer. The activation energies of the films were determined by measuring the dark conductivity from 300 to 575 k using two probe method using pressure contact.

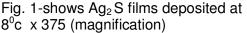
RESULTS AND DISCUSSION

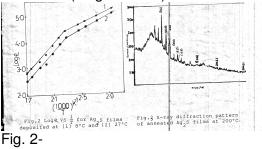
Silver sulphide films have been deposited from acidic medium, using thioacetamide as a sulphur releasing source. The reaction mechamism is proposed as follows.

 $4AgNO_3 + 2CH_3CSNH_2 + 4H^+ \rightarrow 2Ag_2$ S+2CH₃CONH₂+ 4NO₂ + 2H₂O(1)

The film quality was improved at 27° c; the film thickness was increased with decreasing temperature. Fig. 1 shows Ag₂ S films deposited at 8° c bath temperature. The films were uniform and thin.







We have studied the electrical resistivity of the Ag₂S films deposited in the range 8 to 550c. It was found that, resistivity for the deposition at 8°c bath temperature is of the order $1-2 \times 10^5$ ohm cm. fig. 2 shows the plot of log 9 vs 1/T for the Ag₂S films deposited at 8 and 27°C. The plots show two regions to low and high corresponding temperature regions. The value of activation energies in both the regions are 0.069 eV and 0.37 eV at 8°c and and 0.24 eV 0.10 eV at 27°c respectively . X - ray diffraction pattern pw1710 were taken using diffractometer to examine the Ag₂ S It shows that, the films are films. polycrystalline in nature. Fig. 3 shows xray diffraction pattern of annealed Ag₂ S films at 200°c. The observed 'd' values of Ag₂ S are in good agreement with standard 'd' values taken from the ASTM Diffraction Data File are given below. tendered d values

Observed d values	tandared d value
2.832	2.836
2.573	2.583
2.434	2.440
2.412	2.421
2.379	2.383
2.076	2.072
1.962	1.963
1.556	1.554

Optical absorption of Ag₂ S films was studied in the wavelength range of 900 to 2000 nm for the film. The absorption coefficient ' α ' was found to be of the order of 10⁴ to 10⁵ cm⁻¹ above the band gap region. The Ag₂ S films were n type in nature and showed photovoltaic activity in a photoelectrochemical cell formed with 1M (NaoH - Na₂^{S-S}) electrolyte. The ISC \approx 0.1 mA/cm² an Voc \approx 100 mV has been obtained at 100 mW/cm² illumination intensity.